

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	1692	"si.sub."\$4 near3 "ge.sub."\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 16:46
S2	20837	"si.sub."\$6ge\$6 or "ge.sub."\$6si\$6 or si\$1ge or ge\$1si	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 16:48
S3	61964	(si or silicon) near2 (ge or germanium) or S2 or S1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 10:56
S4	135413	epi or epitax\$6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 16:50
S5	159294	poly\$1si or poly\$1silicon or polycrystal\$5 adj2 (si or silicon)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 17:46
S6	2983567	oxide or dioxide or "sio.sub.2" or insulating or insulator or insulation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 16:58
S7	1281445	yield	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 16:54
S8	915	S3 same S4 same S5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 16:54

S10	143723	silane or "sih.sub.4"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 17:01
S12	3232827	dielectric or insulative or S6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 16:59
S13	245	S8 and S10 and S12	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 17:01
S14	159932	poly\$2si or poly\$2silicon or polycrystal\$5 adj3 (si or silicon)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 17:47
S15	55170	single\$2crystal\$5 or mono\$2crystal\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 17:48
S16	669443	poly or polycrystal\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 17:50
S17	188	S3 same S4 same S15 same S16	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 17:53
S18	133345	bipolar or bjt or hbt	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 17:53

S19	108	S17 and S18	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 17:53
S20	1692	"si.sub."\$4 near3 "ge.sub."\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 10:56
S21	20873	"si.sub."\$6ge\$6 or "ge.sub."\$6si\$6 or si\$1ge or ge\$1si	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 10:56
S22	62081	(si or silicon) near2 (ge or germanium) or S21 or S20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:24
S23	1407	(438/488 or 438/489 or 438/507). ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:00
S24	215	S22 and S23	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:00
S25	1410936	yield or throughput	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:01
S26	80	S24 and S25	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:05

S27	4192188	pressure	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:06
S28	3946334	temperature	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:06
S29	3540804	flow	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:07
S30	3229952	thickness or concentration	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:07
S31	202681	S30 with S27	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:24
S32	320127	S30 with S28	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:12
S33	132321	S30 with S29	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:14
S34	11578	S31 and S32 and S33	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:14

S35	32540	batch\$1wise	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:15
S36	22705	growth adj3 (condition or parameter)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:16
S37	403	S34 and S35	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:18
S38	259	S37 and S25	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:18
S39	62081	(si or silicon) near2 (ge or germanium) or S21 or S20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:24
S40	22087	S30 with S27 with (depend\$5 or variable or varies or vary or varying)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:30
S41	396	S39 and S40	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:29
S42	115544	epitax\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:29
S43	90	S41 and S42	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:29

S44	54905	S30 with S28 with (depend\$5 or variable or varies or vary or varying)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:31
S45	13268	S30 with S29 with (depend\$5 or variable or varies or vary or varying)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:32
S46	488	S44 and S39 and S42	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:33
S47	106	S45 and S39 and S42	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:33
S48	22	S43 and S46 and S47	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:42
S49	1198300	monitor\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:43
S50	23	S43 and S49	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:47
S51	154	S46 and S49	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/25 11:47